

Revealing the impact of strontium doping on the optical, electronic and electrical properties of the nanostructured 2H-CuFeO₂ delafossite thin films

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Supplementary Information

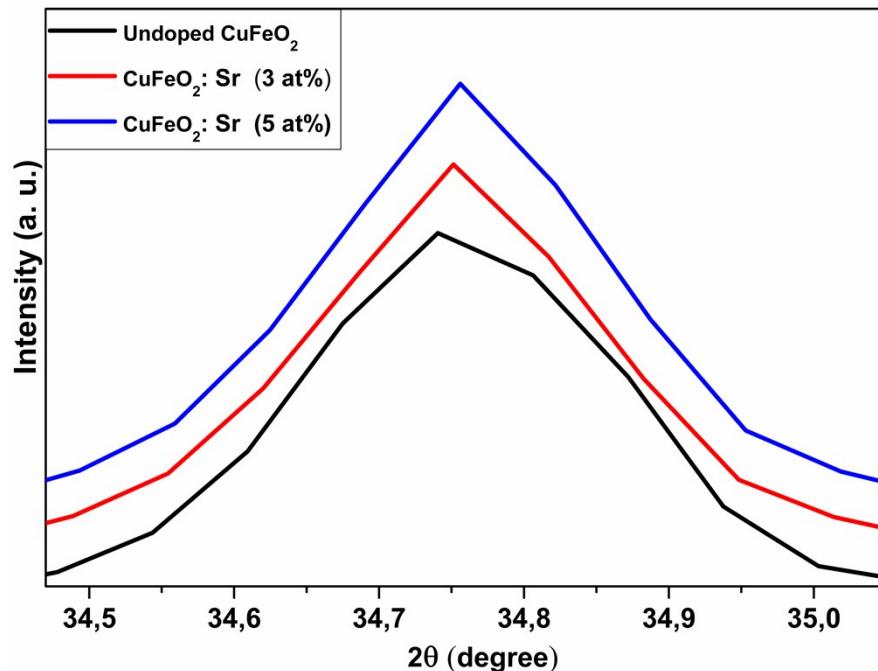


Fig. S1 Magnified XRD peaks in the region of the (101) plane for the pure and Sr-doped CuFeO_2 thin films.

Table S1. Structural parameters of the pure and Sr-doped CuFeO_2 thin films from XRD data; Lattice parameters, Crystallite size.

Compound	Space group	Lattice parameters (\AA)		D (nm)
		a	c	
CuFeO_2	$P6_3/mmc$	3.0532	11.52	27
$\text{CuFeO}_2:\text{Sr}^{2+}$ (3%)	$P6_3/mmc$	3.0514	11.4975	31
$\text{CuFeO}_2:\text{Sr}^{2+}$ (5%)	$P6_3/mmc$	3.0496	11.4802	48

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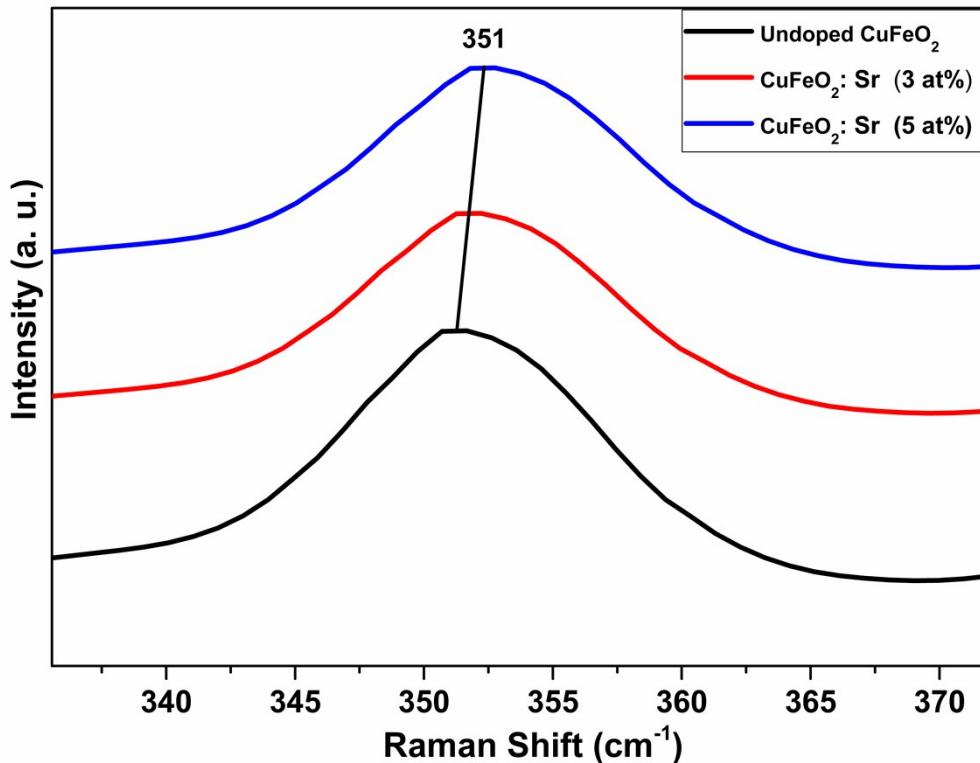
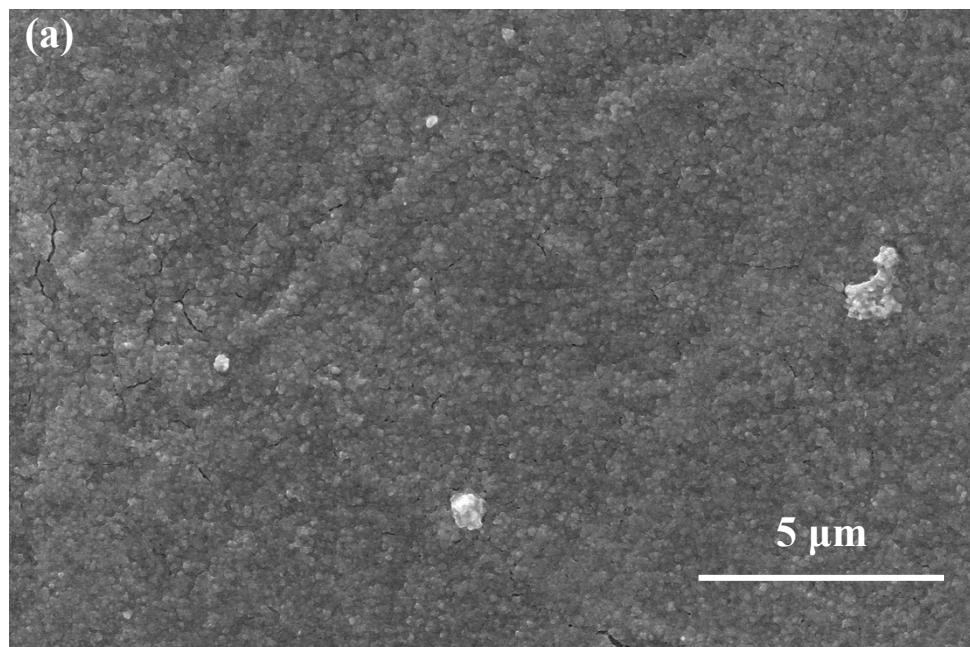


Fig. S2 Magnified Raman signal in the region of the 351 cm^{-1} mode for the pure and Sr-doped CuFeO_2 thin films.



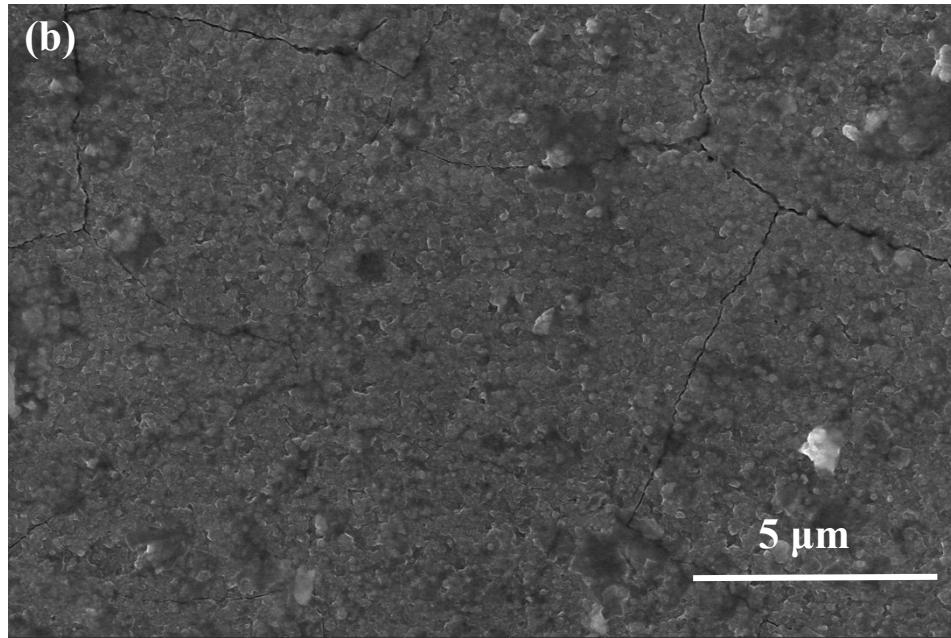


Fig. S3 Top-view of Sr-doped CuFeO₂ thin film **(a)** 3% and **(b)** 5%.

Table S2. Atomic concentrations of the different Cu_{1-2x}Sr_xFeO₂ elements obtained by EDX analysis.

Samples	Atomic percentages			
	Cu	Fe	O	Sr
CuFeO ₂	24.34	24.59	51.07	0
CuFeO ₂ :Sr ²⁺ (3%)	23.10	24.58	51.61	0.71
CuFeO ₂ :Sr ²⁺ (5%)	21.76	24.20	52.94	1.10

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Table S3. Conductivity type, carrier concentration, mobility and resistivity value of the pure and Sr-doped CuFeO₂ thin films.

Samples	Type of conductivity	Carrier concentration (Cm ⁻³)	Mobility μ (cm ² V ⁻¹ s ⁻¹)	Resistivity (Ωcm)
CuFeO ₂	p	5.7.10 ¹⁶	7.9	4.9
CuFeO ₂ :Sr ²⁺ (3%)	p	4.1.10 ¹⁶	9.5	4.3
CuFeO ₂ :Sr ²⁺ (5%)	p	3.6.10 ¹⁶	12.1	3.5